MR4045

Automotive Transient Voltage Suppressor

34 V - 45 V

Designed for Automotive Applications (Alternator) requiring Reverse Avalanche Capability for use as Transient Voltage Suppressor. Developed to suppress transients in automotive systems, this device operates in the forward mode as Standard Rectifier or in Reverse as Transient Voltage Suppressor for Centralized Protection.

For further information referring to Mounting or Operating Conditions, contact your nearest ON Semiconductor Sales Representative.

Mechanical Characteristics

• Finish: 100% Tin Plated
All External Surfaces are Corrosion Resistant

• Weight: 2.6 Grams (Approximately)

Packaging/Labeling

- Two Sealed Bags into a Cardboard Box
- Device Number Labeled on the Bag

Marking

- The Pieces are Laser Marked on the Epoxy of the Diode
- The part, divided into 4 quarters, has the following marking:
 - On the top quarter: 1 digit for the polarity (N or P), 1 digit for the voltage code (2 for 34–45 V), 4 digits for the date code (YYMM)
 - On the left and right quarter: 1 digit for the polarity (N or P)
 - On the bottom quarter: 2 digits for the site code (NL for Czech Republic) and 3 digits for the assembly lot number

MAXIMUM RATING

Rating	Symbol	Value	Unit
DC Blocking Voltage	٧R	30	Volts
Average Forward Current (Single Phase, Resistive Load, T _C = 185°C)	lo	40	Amps
Peak Repetitive Reverse Surge Current (Time Constant = 10 ms, T _C = 25°C) (Time Constant = 80 ms, T _C = 25°C)	I _{RSM} I _{RSM}	55 25	Amps
Non–Repetitive Peak Surge Current (Halfwave, Single Phase, 50 Hz)	IFSM	500	Amps
Storage Temperature Range	T _{stg}	-40 to +200	°C
Maximum Operating Junction Temperature	TJ	200	°C



ON Semiconductor

Formerly a Division of Motorola http://onsemi.com



N SUFFIX (Anode to Cup) P SUFFIX (Cathode to Cup) CASE 193A

ORDERING INFORMATION

Device	Package	Shipping	
MR4045N	Button Can	5000/Box	
MR4045P	Button Can	5000/Box	

THERMAL CHARACTERISTICS

Characteristic		Value	Unit
Thermal Resistance Junction to Case	$R_{ heta JC}$	0.4	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic		Min	Max	Unit
Instantaneous Forward Voltage ⁽¹⁾ (I _F = 100 Amps, $T_C = 25^{\circ}C$)	٧F	_	1.1	Volts
Reverse Current ⁽¹⁾ ($V_R = 28 \text{ Vdc}, T_C = 25^{\circ}\text{C}$)	IR	_	1.0	μΑ
Breakdown Voltage ⁽¹⁾ (I _R = 100 mA, T _C = 25°C)	V _(BR)	34	45	Volts
Breakdown Voltage $ (I_R = 80 \text{ Amps, } T_C = 25^{\circ}\text{C, PW} = 80 \mu\text{s}) $ $ (I_R = 80 \text{ Amps, } T_C = 85^{\circ}\text{C, PW} = 80 \mu\text{s}) $	V(BR)		53 55	Volts
Breakdown Voltage Temperature Coefficient	V(BR)TC	0.0	95*	%/°C
Forward Voltage Temperature Coefficient (I _F = 10 mA)	VFTC	-2	2*	mV/°C

⁽¹⁾ Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2%.

^{*}Typical

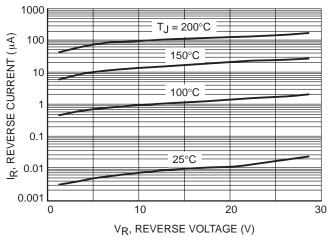


Figure 1. Typical Reverse Current

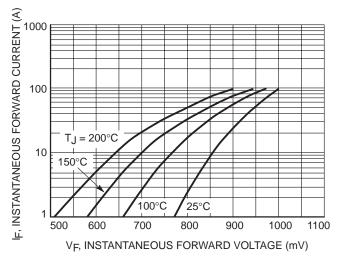


Figure 2. Typical Forward Voltage

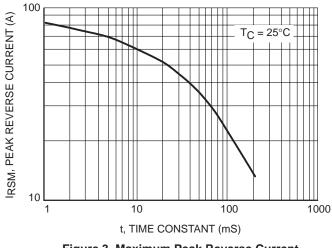


Figure 3. Maximum Peak Reverse Current

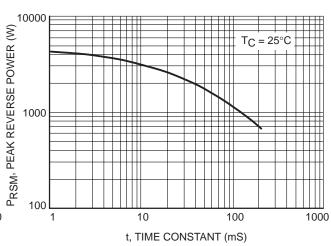


Figure 4. Maximum Peak Reverse Power

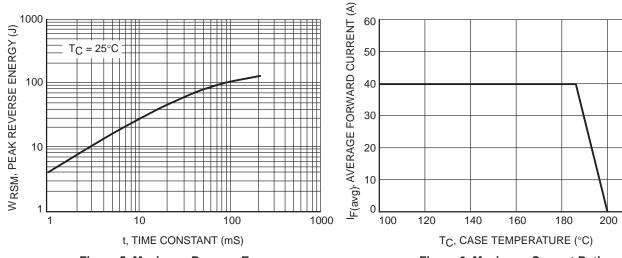


Figure 5. Maximum Reverse Energy

Figure 6. Maximum Current Rating

220

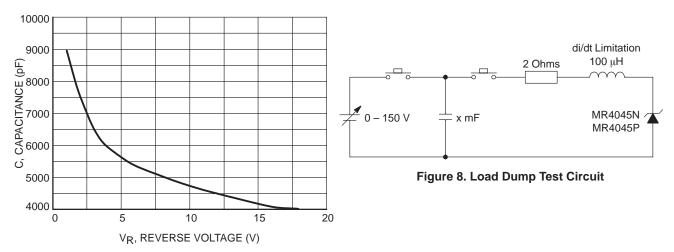


Figure 7. Typical Capacitance

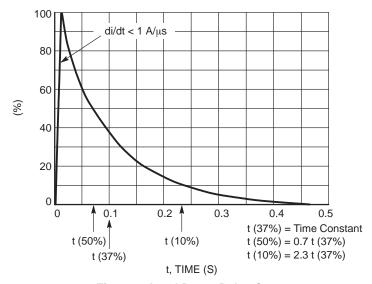
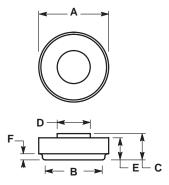


Figure 9. Load Dump Pulse Current

MR4045

PACKAGE DIMENSIONS

N SUFFIX
(Anode to Cup)
P SUFFIX
(Cathode to Cup)
CASE 193A–02
ISSUE A



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	11.4	11.6	0.449	0.457
В	9.3	9.7	0.366	0.382
С	4.3	4.9	0.169	0.193
D	5.4	5.6	0.213	0.220
Ε	3.6	4.2	0.142	0.165
F	1.0	2.0	0.039	0.079

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